

**VOLTAGE RANGE: 20 - 100V**

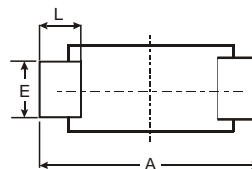
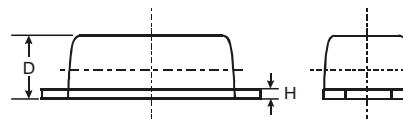
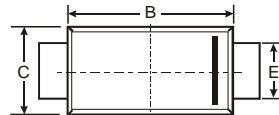
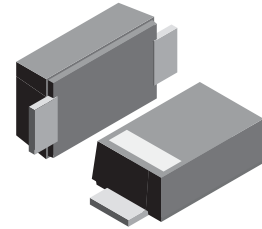
**CURRENT: 2.0 A**

### Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-0

### Mechanical Data

- Case: SMAF, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.0018 ounce, 0.064 grams



SMAF			
Dim	Min	Max	Typ
A	4.75	4.85	4.80
B	3.68	3.72	3.70
C	2.57	2.63	2.60
D	0.097	1.03	1.00
E	1.38	1.42	1.40
H	0.13	0.17	0.15
L	0.63	0.67	0.65
All Dimensions in mm			

### Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SS22AF	SS23AF	SS24AF	SS25AF	SS26AF	SS28AF	SS210AF	Unit
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	V
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	56	70	V
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	V
Maximum average forward rectified current at T <sub>L</sub> (see fig.1)	I <sub>(AV)</sub>	2.0							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	50.0							A
Maximum instantaneous forward voltage at 2.0A	V <sub>F</sub>	0.55		0.70		0.85		V	
Maximum DC reverse current at rated DC blocking voltage <small>T<sub>A</sub>=25°C</small> <small>T<sub>A</sub>=100°C</small>	I <sub>R</sub>	0.5							mA
		20		10					
Typical junction capacitance (NOTE 1)	C <sub>J</sub>	220		180		pF			
Typical thermal resistance (NOTE 2)	R <sub>θJA</sub>	75.0							°C/W
Operating junction temperature range	T <sub>J</sub>	-65 to +125			-65 to +150			°C	
Storage temperature range	T <sub>STG</sub>	-65 to +150							°C

**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.  
2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

## RATINGS AND CHARACTERISTIC CURVES SS22AF THRU SS210AF

AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE

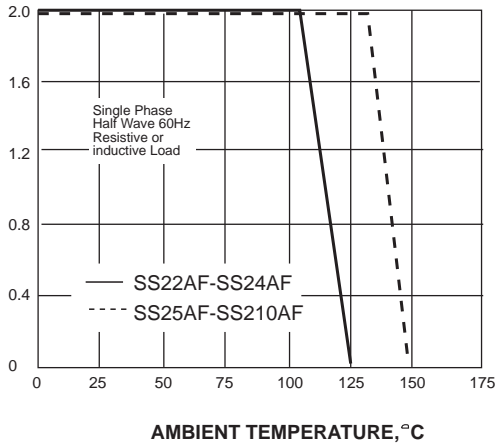


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

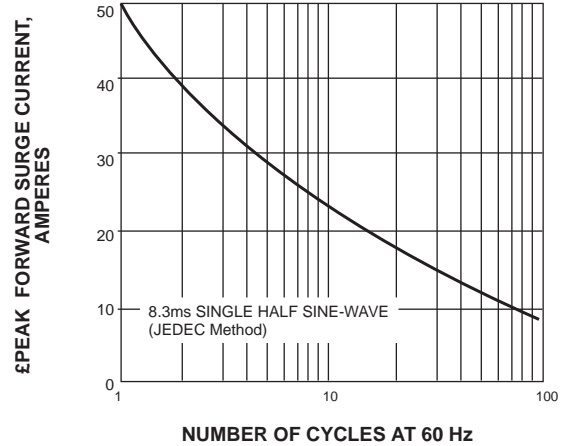


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

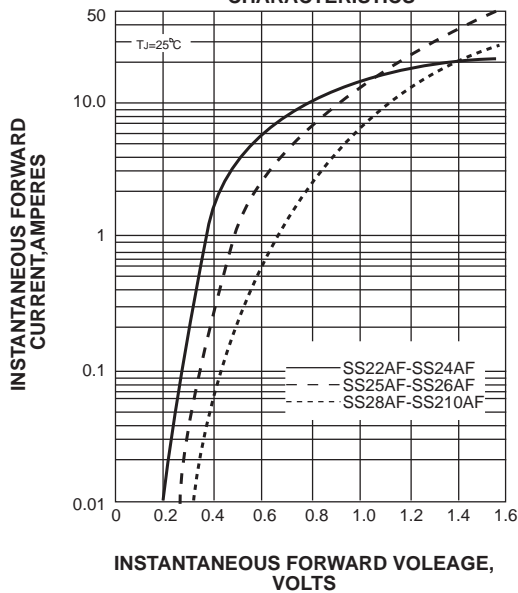


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

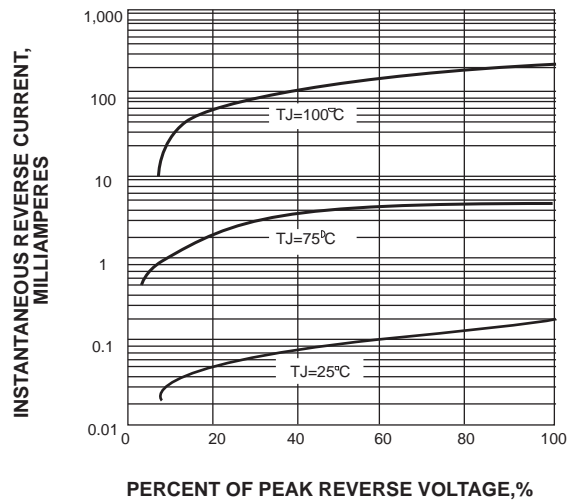


FIG. 5-TYPICAL JUNCTION CAPACITANCE

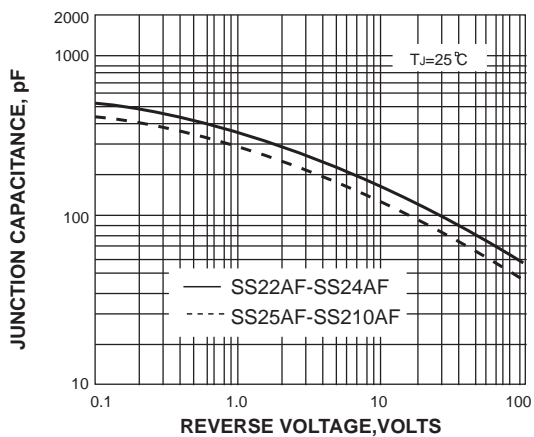


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

